

Preparation and Crystal Structure of MnBiSe₂I

Arno Pfitzner*, Manfred Zabel, and Franz Rau

Regensburg, Institut für Anorganische Chemie der Universität

Received February 18th, 2005.

Dedicated to Professor Gerd Becker on the Occasion of 65th Birthday

Abstract. Black single crystals of MnBiSe₂I were obtained by the reaction of stoichiometric amounts of Mn, Bi, BiI₃, and Se at 600 °C for 7 days. The compound crystallizes in the monoclinic system, space group *C2/m*, with $a = 13.428(2)$, $b = 4.112(1)$, $c = 10.130(2)$ Å, $\beta = 90.97(2)^\circ$, and $Z = 4$. The crystal structure refinement based on 849 reflections converged at $R = 0.0380$ and $wR2 =$

0.0916, respectively. MnBiSe₂I forms a layer structure consisting of MnSe₆ octahedra, MnSe₂I₄ octahedra, and BiSe₃₊₂ pyramids.

Keywords: Manganese; Bismuth; Selenium; Iodine; Sulfosalts; Crystal structure

Introduction

The synthesis of layered materials with interesting magnetic properties on the basis of transition elements usually is focussed on iron, chromium, and manganese containing compounds. A mineral related group of compounds containing these ions are the so-called sulfo salts, e.g. FeSb₂S₄ (berthierite) [1]. Inspired by a publication dealing with a layered material of this composition, namely MnBi₂S₄ [2], we recently started to elucidate the existence of further sulfo salts of Mn²⁺, which usually occurs as a d^5 high spin ion in octahedral environment in these compounds. It was shown that MnSb₂S₄ can be obtained either by hydrothermal methods as an orthorhombic compound which is isotopic to FeSb₂S₄ [3], i.e. *oP28*, or by solid state reactions as a monoclinic phase *mC28* which is closely related to MnBi₂S₄ [4]. The homologous MnSb₂Se₄ *mC28* could also be obtained by solid state preparation [5]. Spin polarized DFT calculations confirmed the semiconducting behaviour of both phases of MnSb₂S₄ [5, 6]. Neutron powder diffraction experiments on MnSb₂S₄ *mC28* and the heavier homologous compounds revealed that these compounds become antiferromagnetic below about 25 K. The magnetic spins show a complicated helical ordering pattern [5, 7]. Manganese ions are octahedrally coordinated by chalcogenide ions in these materials. The MnQ₆ octahedra (Q = S, Se) share common edges to give strands of octahedra along one crystallographic direction. These strands of octahedra are interlinked by chalcogenometalate ions to form layers, which are stacked above each other with weak interlayer interactions [4]. It is interesting to prepare new layered magnetic materi-

als by changing the connectivity of these strands of octahedra by chemical modification of the compounds. Thus, new ordering patterns of the spins can be expected. One way how to change the connectivity is the partial substitution of chalcogenide ions by halide ions. Two examples for such compounds were recently described: monoclinic MnSbSe₂I *mC20* [8] and orthorhombic MnSbS₂Cl *oP20* [9]. The different radii of the constituting ions have obviously a certain influence on the structural arrangement of the resulting compounds. Thus, we find two different types of octahedra MnSe₆ and MnSe₂I₄ in MnSbSe₂I but only one type of octahedra MnS₄Cl₂ in MnSbS₂Cl. The different octahedra in MnSbSe₂I share common edges formed either by two Se atoms or by two I atoms, respectively. In contrast, only common edges formed by one S and one Cl atom are found in MnSbS₂Cl. These strands of octahedra share common Q vertices in MnSbSe₂I and also in MnSbS₂Cl. The introduction showed up the close relations of MnSb₂Q₄ and MnBi₂Q₄. Thus, we prepared the heavier homologous compound MnBiSe₂I and determined the crystal structure in order to further check the influence of the different ionic radii on the observed crystal structures.

Results

Structure determination

Single crystals of the title compound suitable for a structure determination could be obtained from different synthetic routes, see the experimental section for details. X-ray intensities were collected on a STOE IPDS-I using MoK α radiation, $\lambda = 0.71073$ Å. The compound crystallizes in the monoclinic system with the lattice constants $a = 13.428(2)$, $b = 4.112(1)$, $c = 10.130(2)$ Å, $\beta = 90.97(2)^\circ$, $V = 559.3(1)$ Å³, and $Z = 4$. The space group *C2/m* was derived from systematic extinctions and confirmed by the subsequent refinement. Direct methods were applied to solve the structure and provided the positions of one Bi, one I, two Se and two Mn atoms. The refinement converged at

* Prof. Dr. A. Pfitzner
Institut für Anorganische Chemie
Universität Regensburg
D-93040 Regensburg (Germany)
Fax: +49 941 943 4983
E-mail: arno.pfitzner@chemie.uni-regensburg.de

$R = 0.0359$ for reflections with $I > 2\sigma_I$ and $R = 0.0380$ for all reflections. A total of 849 independent reflections was used for the refinement of 34 parameters. Anisotropic displacement parameters were used for all atoms. An extinction parameter was included in the last refinement cycles. Further crystallographic details are summarized in Table 1. Atomic coordinates and anisotropic displacement parameters are collected in Table 2 and Table 3, respectively. Table 4 contains selected interatomic distances and angles calculated from these data.

Table 1 Crystallographic data for the structure analysis of MnBiSe₂I

Compound	MnBiSe ₂ I
Formula weight in g mol ⁻¹	548.74
Crystal size in mm ³ and colour	0.1 x 0.1 x 0.07, black
Crystal system	monoclinic
Space group	<i>C2/m</i> (No. 12)
Lattice constants in Å	$a = 13.428(2)$ $b = 4.112(1)$ $c = 10.130(2)$ $\beta = 90.97(2)^\circ$
Cell volume, <i>Z</i>	559.3(1) Å ³ , 4
ρ_{calc} in g cm ⁻³	6.517
Diffractometer	STOE IPDS-I, MoK α , $\lambda = 0.71073$ Å, oriented graphite monochromator
ϕ -range in $^\circ$, $\Delta\phi$ in $^\circ$	$0.0 \leq \phi \leq 191.8$, 1.4
$\mu(\text{MoK}\alpha)$ in mm ⁻¹	52.05
Absorption correction	numerical, crystal description with 7 faces, shape optimizes with X-SHAPE [10]
No. of measured images	137
Irradiation time/image in min	8
Temperature in $^\circ\text{C}$	20
2θ -range in $^\circ$	$4.2 \leq 2\theta \leq 58.6$
<i>hkl</i> -range	$-16 \leq h \leq 18$ $-5 \leq k \leq 5$ $-13 \leq l \leq 13$
No. of reflections, R_{int}	2875, 0.0463
No. of independent reflections	849
No. of parameters	34
Program	SHELX 97 [11]
Final R/wR ($I > 2\sigma_I$)	0.0359, 0.0906
Final R/wR (all reflections)	0.0380, 0.0916
GooF	1.054
Largest difference peak $\Delta\rho_{\text{max}}$ and hole $\Delta\rho_{\text{min}}$ in e Å ⁻³	2.238 -1.772

Further details of the crystal structure investigations are available from the Fachinformationszentrum Karlsruhe, D-76344 Eggenstein-Leopoldshafen (Germany), Fax: 0049 7247 808 666, E-mail: crysdata@fiz-karlsruhe.de, on quoting the depository number CSD-415138, the name of the authors, and the reference of the publication.

Table 2 Atomic coordinates and equivalent isotropic displacement parameters U_{eq} in Å² for MnBiSe₂I

Atom	<i>x</i>	<i>y</i>	<i>z</i>	U_{eq}^a
Bi	0.2092(1)	0	0.8102(1)	0.024(1)
Mn1	0	1/2	0	0.024(1)
Mn2	0	1/2	1/2	0.025(1)
I	0.1371(1)	0	0.4266(1)	0.024(1)
Se1	0.1364(1)	0	0.0570(1)	0.020(1)
Se2	0.0714(1)	1/2	0.7559(1)	0.020(1)

^a U_{eq} is defined as one third of the trace of the orthogonalized U_{ij} tensor.

Structure description and discussion

MnBiSe₂I crystallizes isotypic with MnSbS₂I. The coordination spheres of the metal ions are shown in Figure 1.

Table 3 Anisotropic displacement parameters U_{ij} in Å² for MnBiSe₂I. $U_{12} = U_{23} = 0$

Atom	U_{11}	U_{22}	U_{33}	U_{13}
Bi	0.024(1)	0.023(1)	0.024(1)	0.004(1)
Mn1	0.024(1)	0.024(1)	0.023(1)	0.004(1)
Mn2	0.026(1)	0.023(1)	0.026(1)	0.001(1)
I	0.022(1)	0.022(1)	0.028(1)	0.004(1)
Se1	0.020(1)	0.021(1)	0.020(1)	0.000(1)
Se2	0.022(1)	0.019(1)	0.020(1)	-0.001(1)

Table 4 Selected interatomic distances (in Å), and angles (in degrees) for MnBiSe₂I at room temperature

Bi-Se1	2.700(1)	Se1-Bi-Se1	79.94(3)
Bi-Se2	2 x 2.8140(8)	Se1-Bi-Se2	2 x 81.55(3)
Bi-Se1	2 x 3.201(1)	Se1-Bi-Se2	2 x 86.22(3)
		Se2-Bi-Se1	2 x 91.83(2)
Mn1-Se2	2 x 2.667(1)	Se2-Bi-Se2	93.89(4)
Mn1-Se1	4 x 2.8069(8)	Se2-Bi-Se1	2 x 166.12(3)
		Se1-Mn1-Se1	2 x 180
Mn2-I	4 x 2.8666(6)	Se2-Mn1-Se2	180
Mn2-Se2	2 x 2.748(1)	Se1-Mn1-Se1	2 x 85.80(3)
		Se1-Mn1-Se2	4 x 86.98(3)
		Se1-Mn1-Se2	4 x 93.02(3)
		Se1-Mn1-Se1	2 x 94.20(3)
		I-Mn2-I	2 x 180
		Se2-Mn2-Se2	180
		Se2-Mn2-I	4 x 88.32(3)
		I-Mn2-I	2 x 88.34(2)
		I-Mn2-I	2 x 91.66(2)
		Se2-Mn2-I	4 x 91.68(3)
		Mn2-I-Mn2	91.66(2)
		Mn1-Se2-Mn2	138.52(5)

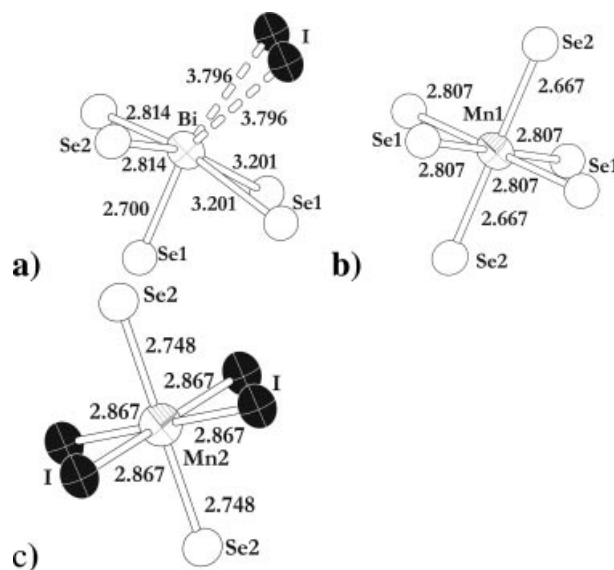


Figure 1 Coordination spheres of the metal ions in MnBiSe₂I, distances are given in Å. Displacement parameters are drawn at the 95% probability level.

The bismuth atom is exclusively coordinated by Se atoms in its first coordination sphere. As shown by the distances and angles the coordination of Bi towards Se can be regarded as 3 + 2, i.e. we find the typical arrangement for

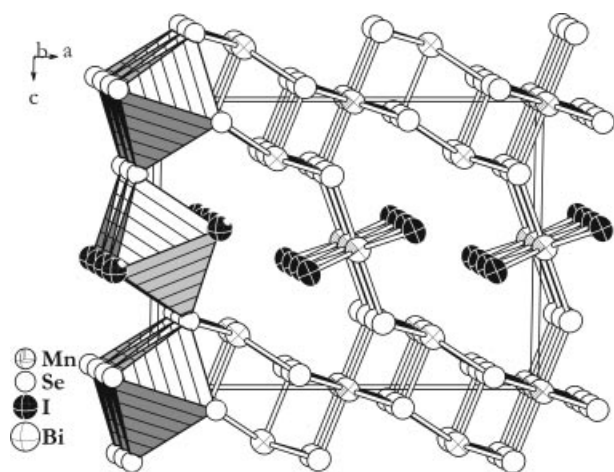


Figure 2 Section of the crystal structure of MnBiSe₂I. Mn atoms are octahedrally coordinated and the octahedra form chains along *b*. BiSe₃₊₂ units connect the chains to form layers parallel (001).

sulfo salts. Three short bonds $d(\text{Bi-Se})$ are in the range from 2.700–2.814 Å, and two medium range bonds $d(\text{Bi-Se}) = 3.201$ Å are found. Two iodine atoms are located in a long distance $d(\text{Bi-I}) = 3.796$ Å. These distances $d(\text{Bi-I})$ are much longer than those found in BiI₃, $d(\text{Bi-I}) \leq 3.124$ Å [12]. Manganese ions are six-coordinate, either only by selenide ions or by four iodide ions and two selenium ions. Both types of octahedra show two short axial bonds, i.e. $d(\text{Mn-Se}_2) = 2.667$ Å for [MnSe₆] and $d(\text{Mn-Se}_2) = 2.748$ Å for [MnSe₂I₄]. The distances in the basal plane are longer, namely $d(\text{Mn-Se}_1) = 2.807$ Å for [MnSe₆] and $d(\text{Mn-I}) = 2.867$ Å for [MnSe₂I₄]. Having the connectivity of the octahedra in mind, one finds a compression along the direction of the common vertices Se₂, i.e. [001]. The longer bonds are found in the direction of the chains of octahedra, i.e. [010], see Figure 2.

The distances of the manganese atom to the surrounding atoms are similar to those found in the isotypic compound MnSbSe₂I [8]. Obviously the monoclinic structure type is preferred for the present combination of elements. The volumes of the unit cells of MnSbSe₂I ($V = 543$ Å³) and of MnBiSe₂I ($V = 559$ Å³) differ only slightly, especially when the measuring temperature of 153 K for MnSbSe₂I is taken into account. The same is found for the couple MnSb₂S₄ ($V = 669$ Å³) and MnBi₂S₄ ($V = 672$ Å³). Obviously the volume which is occupied by the tri-valent cations Sb³⁺ and Bi³⁺ is almost the same. This is probably due to the fact that the difference between short bonds Sb-Q and long bonds Sb-Q (the so-called non bonding distances) is much bigger than in case of Bi-Q, where these distances are

evened out to a certain degree. In case of MnSbS₂Cl [9] the bonds Mn-Cl are significantly shorter than the bonds Mn-S. This results in a modified coordination behaviour of the manganese atoms and a completely different three dimensional crystal structure is formed. At the moment MnBiS₂Br is under investigation and this compound is also isotypic with MnBiSe₂I and MnSbSe₂I, due to similarly long bonds Mn-Br as compared to Mn-S. In this case the monoclinic angle $\beta = 90.87^\circ$ is even closer to 90° than in MnBiSe₂I [13].

Experimental Section

MnBiSe₂I was obtained either by reaction of stoichiometric amounts of Mn, BiI₃, Bi, and Se (3 : 1 : 2 : 6) or by reaction of Mn₃Bi₂Se₆ with BiI₃ (1 : 1). Both reaction mixtures were sealed in evacuated quartz ampoules and then heated to 600 °C for 7 days. The title compound was isolated as black shiny needle shaped crystals. However, in both cases no phase pure product could be obtained. The by-products could not yet be identified in detail. However, MnSe is always one of the impurities.

X-ray powder diffraction patterns were recorded on a Stoe STADI P running with germanium monochromatized CuK α_1 radiation. Single crystals were fixed on thin walled glass capillaries and then mounted on a Stoe IPDS single crystal diffractometer providing monochromatic MoK α radiation. Crystallographic data are collected in Table 1. Absorption was corrected after the optimization of the description of the crystal shape with the X-SHAPE routine [10].

Acknowledgement. Financial support of the University of Regensburg and the State of Bavaria is gratefully acknowledged. We thank Fabian Dielmann for some experimental help.

References

- [1] M. J. Buerger, Th. Hahn, *Am. Miner.* **1950**, *40*, 226.
- [2] S. Lee, E. Fischer, J. Czerniak, N. Nagasundaram, *J. Alloys Compds.* **1993**, *197*, 1.
- [3] K. Bente, A. Edenharter, *Z. Kristallogr.* **1989**, *186*, 31.
- [4] A. Pfitzner, D. Kurowski, *Z. Kristallogr.* **2000**, *215*, 373.
- [5] D. Kurowski, Ph.D. thesis, Universität Regensburg, **2003**.
- [6] S. F. Matar, R. Wehrich, D. Kurowski, A. Pfitzner, submitted.
- [7] D. Kurowski, A. Pfitzner, W. Kockelmann, M. H. Möller, R. Pöttgen, in preparation.
- [8] O. Tourgait, J. A. Ibers, A. Mar, *Acta Crystallogr.* **2003**, *C59*, i77.
- [9] C. Doussier, P. Léone, Y. Moëlo, *Solid State Sci.* **2004**, *6*, 1387.
- [10] X-SHAPE, STOE, Darmstadt **1996**.
- [11] G. M. Sheldrick, SHELX 97 Programs for the solution and refinement of crystal structures, University of Göttingen, Germany, **1997**.
- [12] M. Ruck, *Z. Kristallogr.* **1995**, *210*, 650.
- [13] A. Pfitzner, M. Zabel, F. Rau, *Monatsh. Chem.*, in press.